Chemical Science



REVIEW

View Article Online
View Journal | View Issue



Cite this: Chem. Sci., 2025, 16, 2136

Opportunities and challenges of lead-free metal halide perovskites for luminescence

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Metal halide perovskites (MHPs) have been developed rapidly for application in light-emitting diodes (LEDs), lasers, solar cells, photodetectors and other fields in recent years due to their excellent photoelectronic properties, and they have attracted the attention of many researchers. Perovskite LEDs (PeLEDs) show great promise for next-generation lighting and display technologies, and the external quantum efficiency (EQE) values of polycrystalline thin-film PeLEDs exceed 20%, which is undoubtedly a big breakthrough in lighting and display fields. However, the toxicity and instabilities of lead-based MHPs remain major obstacles limiting their further commercial applications. The exploration and development of lead-free MHPs (LFMHPs) are regarded as the most facile strategies to solve these problems. Compared with lead-based perovskites, LFMHPs exhibit better stabilities and broadband emission. With continuous development of LFMHPs, their photoluminescence quantum yields (PLQYs) have reached 99%, facilitating their use as ideal emitters. In this review, the structures and features of LFMHPs are analyzed, and the preparation methods of LFMHPs with various structures and configurations are discussed. Then, the mechanisms and strategies for improving the emission performance of white LEDs based on LFMHPs are demonstrated. Finally, their challenges in commercial production and perspectives are prospected.

Received 22nd June 2024 Accepted 23rd October 2024

DOI: 10.1039/d4sc04119d

rsc.li/chemical-science

Introduction

In the field of solid-state lighting technology, white-light-emitting diodes (WLEDs) have been identified as ideal light sources to replace incandescent bulbs due to their long lifetime, low energy consumption, wide spectrum, and controllability of color temperature.¹ Light-emitting diodes (LEDs) were first demonstrated from the development of gallium nitride (GaN)-based semiconductors in the early 1990s.² As one of the 2014 Nobel Prize winners, Nakamura created a representative high-brightness blue GaN-LED with an external quantum efficiency of 7.20% in 1993, which shows good prospects for application in WLEDs. Therefore, WLEDs have gradually been recognized as excellent candidates in cost-effective and high-efficiency solid-state lighting.¹-10

As a new type of semiconductor material, metal halide perovskites (MHPs) possess many advantages,¹¹ such as high photoluminescence quantum yields, tunable bandgaps,¹² high carrier mobility,¹³ solution processibility,¹⁴ and low preparation cost.¹⁵ All of these superior photoelectronic properties give MHPs great potential to perform well in LEDs.^{11,13,14,16-23} MHPs are materials with the formula ABX₃ with a crystal structure

similar to that of the mineral perovskite CaTiO3, where A is a monovalent cation, such as CH₃NH₃⁺ (MA⁺), CH(NH₂)⁺ (FA⁺), and Cs⁺; B is a bivalent metal cation, such as Pb²⁺, Sn²⁺, Cu²⁺, (Ag⁺ and Bi³⁺ are double perovskites); and X represents the halide anions, including Cl-, Br-, and I-. By changing the halogen and cation composition,24 the structures and chemical bonds of MHPs can be regulated, resulting in changes to their photoelectronic properties. With the further study of perovskites, novel A₂BX₄, A₃BX₆ and A₃B₂X₅ metal halide perovskites are now being researched in addition to the classic ABX3 metal halides. Since Tan et al. fabricated the first LEDs based on solution-processed organometallic halide perovskites in 2014,25 perovskite-based LEDs have been developed. In just a few years, internal quantum efficiencies (IQEs) and external quantum efficiencies (EQEs) of perovskite LEDs (PeLEDs) increased from 3.4% and 0.76% in the near-infrared region and 0.4% and 0.1% in the green-light region to more than 20% in the nearinfrared26,27 and green-light28 regions, respectively. Due to the excellent photoelectronic performance of MHPs and the rapid development of PeLEDs, certain progress has been made in the material preparation and device fabrication of WLEDs. For example, warm and cold WLEDs were achieved by incorporating 1% and 10% Sb³⁺ doped Cs₂ZrCl₆ on a 310 nm UV-LED chip, respectively.29 However, the inherent toxicity of lead, the complex preparation process, and the low operational lifetime of PeLEDs, as well as their instability under high temperature, light, humidity and other conditions, 16,17,30 limits the application of MHPs in solid-state lighting.31,32

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To solve these problems, lead-free metal halide perovskites (LFMHPs), in which Pb²⁺ ions are completely replaced by bivalent cations, such as Sn²⁺, Ge²⁺, and Zn²⁺, ³³ have been studied and applied in photoelectronic applications. Additionally, ions with different valence states can also replace Pb2+ ions, such as trivalent Sb3+,34 Eu3+, Tb3+,35 and monovalent Cu+,36 and this occurs via heterovalent substitution. At the same time, replacing Pb2+ in a perovskite with monovalent, trivalent and quadrivalent cations, as well as vacancies, can not only improve perovskite stability, but also lead to enhancement of their photoelectronic properties. For LFMHPs, their band gap values can be adjusted according to the different metal components, so that more stable electroluminescence in LEDs can be obtained. The outstanding performance of LFMHPs has attracted the attention of many researchers, and up to now, there has been a lot of progress in WLEDs based on LFMHPs. Sb³⁺-doped Cs₂InCl₅·H₂O:Sb³⁺ exhibits broadband yellow light emission, and its PLQY is as high as 95.5%.34 Cs2AgInCl6 prepared by Li et al. exhibited an enhanced PLQY of 87.2%, assisted by sodium (Na⁺) alloying and bismuth (Bi³⁺) doping, and was used in WLEDs to achieve efficient white-light emission with International Commission on Illumination (CIE) color coordinates of (0.38, 0.44)37 and a color render index (CRI) of 87.8, showing remarkable operational stability under ambient conditions. In this review, the structures and characteristics of LFMHPs are firstly analysed, and preparation methods of LFMHPs with different structures and configurations are discussed. Furthermore, mechanisms, key parameters and strategies for improving the luminous efficiencies of WLEDs based on LFMHPs are described. Finally, their challenges and prospects in commercial applications are discussed (Fig. 1).

Structures, dimension and optical properties of LFMHPs

As is well-known, perovskite configurations can be divided into zero-dimensional (0D), one-dimensional (1D), two-dimensional (2D) and three-dimensional (3D) according to their atomic arrangement order. In addition, perovskites can exist in various structures, such as nanocrystals (NCs), powders, thin films, and single crystals. Different structures can affect the photoelectronic performance of LFMHPs and PeLEDs.38 Similar to traditional 3D Pb-based perovskites, 3D LFMHPs possess a 3D configuration, where corner-shared [BX₆]⁴⁻ octahedra are the basic units.39 In a [BX₆]⁴⁻ octahedron, a metal cation is located in the center of the octahedron surrounded by monovalent cations (e.g. Cs⁺, Rb⁺, and CH₃NH₃⁺). For example, Sn(II)-based $ASnX_3$ perovskites (X = Cl⁻, Br⁻, I⁻) show a similar threedimensional configuration, as shown in Fig. 2a.40 By introducing larger cations such as butylammonium (BA) and phenethylamine (PEA), the 3D octahedral framework can be isolated into octahedral layers with shared angles, resulting in reduction of dimension from 3D to 2D. 2D perovskites can be viewed as a plate or layer cut along a crystallographic direction. By cutting 3D perovskites along the (001) plane, Ruddlesden-Popper-type $(R_2A_{n-1}M_nX_{3n+1}, R = 1^+ \text{ cation})$ or Dion-Jacobsontype $(RA_{n-1}M_nX_{3n+1}, R = 2^+ \text{ cation})$ perovskites can be obtained.46,47 For two typical perovskites with layered structures, Asite ions are regarded as organic ligands. The dimension of LFMHPs can be further reduced to 1D with side- and angularshared chains (formula A₃BX₆), 48 and unconnected (isolated) octahedral 0D structures (formula A₃B₂X₆).49

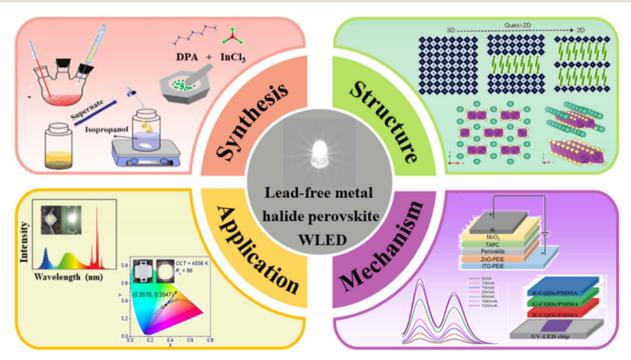


Fig. 1 Summary of the review, which includes synthesis and structures of LFMHPs, as well as mechanisms and applications of WLEDs based on LFMHPs.

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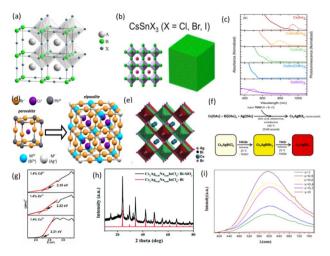


Fig. 2 (a) ABX₃ perovskite structure. BX₆ corner-sharing octahedra are in evidence.⁴⁰ Copyright 2008 American Chemical Society. (b) Structure of CsSnX₃.41 Copyright 2016 American Chemical Society. (c) Absorption and steady-state PL of NCs containing pure and mixed halogens.41 Copyright 2016 American Chemical Society. (d) Structure of double perovskites with M+ and M3+ ions replacing Pb2+ ions.42 Copyright 2018 American Chemical Society. (e) Crystal structure of cubic Cs₂AgBiBr₆.⁴³ Copyright 2018 American Chemical Society. (f) Synthesis diagram of Cs₂AgBiX₆ NCs.⁴² Copyright 2018 American Chemical Society. (g) Tauc plots for 1.4% Cd²⁺, 1.4% Zn²⁺, and 1.4% Cu²⁺-doped Cs₂AgInCl₆, respectively.⁴⁴ Copyright 2020 American Chemical Society. (h) XRD of $Cs_2Ag_{0.40}Na_{0.60}InCl_6:Bi-SiO_2.$ ⁴⁵ Copyright 2021 Royal Society of Chemistry. (i) Emission spectra of Cs₂- $Ag_{1-x}Na_xInCl_6:Bi$ (x = 0, 0.2, 0.4, 0.6, 0.8, 1).¹⁴ Copyright 2021 Electrochemical Society.

3D LFMHPs

In 2014, Felix Deschler et al.25 prepared methylammonium iodide (CH3NH3I) by a solvent evaporation method, and then dissolved CH₃NH₃I and lead(II) chloride (PbCl₂) in anhydrous N,N'-dimethylformamide at a 3:1 molar ratio. CH₃NH₃PbI_{3-x}- Cl_x thin films were prepared by spin-coating from a precursor solution. The photoluminescence (PL) observed from CH3-NH₃PbI_{3-x}Cl_x thin films are mainly attributed to recombination of free charges (electron and hole) within the films. At room temperature, free charges are formed under 1 ps photoexcitation and exhibit a long lifetime, resulting in very efficient PL with a high PLQY of 70%. This reveals the potential of 3D perovskite semiconductors in emission applications due to their facile processing and high luminous efficiency. Additionally, Protesescu et al. have opened a new avenue for the development of MHPs by designing highly efficient perovskite colloidal quantum dots (QDs).50 They synthesized CsPbX3 QDs using a simple preparation method and the emission of the prepared perovskites was in the visible region of 410-700 nm with PLQYs up to 90%, indicating tunable bandgap values of MHPs. It can be seen that photoelectronic performance of QDs is better than that of thin films, and their enhanced PLQYs and stabilities enable them to be applied in PeLEDs.

Subsequently, Jellicoe et al. reported nontoxic LFMHP CsSnX₃ nanocrystals (NCs), which were synthesized by a hotinjection method.41 As demonstrated in Fig. 2b, the prepared CsSnX₃ NCs possess a compact cubic structure. With the change of halogen in CsSnX₃ NCs, their optical spectra were found to extend from the visible-light range to the near-infrared (NIR) region (Fig. 2c). Owing to similar atomic sizes and orbital structures of Sn²⁺ ions with those of Pb²⁺ ions, Sn-based LFMHPs exhibit ideal 3D perovskite structures, but the measured PLQYs of CsSnX3 are below 1%, which results from the existence of high-density defects. It has been found that the defect formation energy in Sn-based perovskites is as low as 250 meV, which leads to defect densities of up to $\sim 10^{19}$ cm⁻³. Due to excellent stabilities and photoelectronic properties of threedimensional lead-free double perovskites, they have attracted the attention of a large number of researchers. The density functional theory (DFT) results show that their stabilities can be evaluated with proper t (tolerance factor) and μ (octahedral factor) values (0.813 < t < 1.107, 0.337 < μ < 0.895), indicating 3D structures and good photoelectronic performance of leadfree double perovskites. For example, Cs2AgBiBr6 and Cs2-AgInCl₆ were characterized and found to possess 3D structures, in which Ag⁺ and Bi³⁺ (In³⁺) together replace a pair of adjacent B2+ ions and then form two octahedrons with halogens, as demonstrated in Fig. 2d. In 2018, Zhou et al. prepared Cs2-AgBiBr₆ double perovskite NCs by the hot-injection method, and their structure is shown in Fig. 2e. Cs2AgBiBr6 NCs possess good photoelectronic properties and stabilities under high temperature and humidity. However, it has been reported that most double perovskites exhibit indirect band structures, resulting in weak PL performance.43 In addition, a series of Cs₂AgBiX₆ NCs composed of different halogens were prepared by an ion exchange method. Sidney E. et al. prepared Cs₂AgBiX₆ (X = Cl, Br) NCs by the hot-injection method. The synthesis and conversion diagram of Cs2AgBiX6 NCs in Fig. 2f further demonstrates that Cs₂AgBiI₆ can be synthesized by an anion exchange reaction. The product maintains the symmetry of cubic Fm3m with the structure of CsAgBiBr₆.⁴² During the ion exchange process, the spectral characteristics of larger-size NCs illustrate their broadband emission with low-energy shifts, as well as an adjusted emission range in the 350-600 nm region. Furthermore, Yang et al. measured the carrier dynamics of double perovskite nanocrystals using time-resolved PL and femtosecond (fs) transient absorption (TA) spectroscopies, and found that the double perovskite NCs show an obvious subband-gap capture process, which originates from surface defects. To solve this problem, they used the surfactant oleic acid (OA) as ligands to passivate the defects, increasing the PLQY by 100 times. Even so, the PLQY is only 6.7%.52 Li et al. proposed the Al3+ doping strategy to change an indirect band gap of Cs₂AgBiX₆ into a direct band gap, thus enhancing its PL performance. As a result, its PLQY was improved to 17.2% and white LEDs with a CRI of 81 were fabricated by integrating Cs₂AgBiX₆ with K₃SbCl₆ on 365 nm UV chips.⁵³

Among reported lead-free double perovskites, Cs2AgInCl6 has the characteristics of a direct band gap. Locardi et al. synthesized intrinsic double perovskite Cs2AgInCl6 NCs by using a colloidal method. They are stable in air and exhibit broadband white-light emission. The PL emission intensity of Mn-doped Cs₂AgInCl₆ NCs increases as the Mn doping

concentration increases from 0.5% to 1.5%, and the highest PLQY achieved was $16 \pm 4\%.^{54}$ In order to better understand the mechanism of the doping strategy, Liao *et al.* doped Cu²⁺, Zn²⁺ and Cd²⁺ ions into Cs₂AgInCl₆ NCs, and the subsequent band gap values were 2.21 eV, 2.22 eV and 2.30 eV, respectively. The influence of different dopants on direct gaps shows that metal dopants enable the band gaps in Cs₂AgInCl₆ to be changed (Fig. 2g).⁴⁴

In 2021, Li et al. synthesized Bi³⁺-doped Cs₂Ag_xNa_{1-x}InCl₆ QDs by the hot-injection method. Based on the broadband spectrum originating from self-trapped excitons in Bi3+-doped Cs₂Ag_xNa_{1-x}InCl₆, they obtained excellent white light emission. The best PLQY of Cs₂Ag_xNa_{1-x}InCl₆ was achieved by doping a small amount of Bi³⁺ ions. The PLQY increased to 57.3%, and the emission peak at 600 nm was obvious. The Na-alloy and Bidoped Cs₂Ag_xNa_{1-x}InCl₆ QDs possess the same cubic structure as Cs₂AgInCl₆. The stability of the QDs was further improved by preparing Cs₂Ag_xNa_{1-x}InCl₆:Bi-SiO₂ thin films using perhydropolysilazane as the coating precursor, which was confirmed from Fig. 2h. XRD patterns of the $Cs_2Ag_{0.40}Na_{0.60}InCl_6$:Bi-SiO₂ thin films exhibited dominant peaks of SiO₂ and Cs₂Ag_{0.40}-Na_{0.60}InCl₆ QDs. Compared with Cs₂Ag_{0.40}Na_{0.60}InCl₆:Bi QDs at room temperature, they exhibited nearly all the main diffraction peaks, therefore the temperature change did not cause a phase transition of the QDs, and it could be concluded that SiO2 plays a protective role and thus prevented the phase transition of the QDs. It is known that coating passivation can inhibit surfacerelated non-radiative processes and PL intensity is improved after sufficient coating. In addition, after heat treatment at 200 °C, the PL intensity of the film based on coating QDs is enhanced, and its PLQY is higher than that of uncoated QDs. 45 Subsequently, Wang et al. studied the phase structures, morphologies and luminescence properties of Cs₂Ag_{1-x}Na_xInCl₆:Bi with different Na contents. Cs2Ag1-xNaxInCl6:Bi has a wide emission peak at 600 nm, as shown in Fig. 2i. When x = 0.8, its PLQY reaches 86.91%, which has been identified as the best value among reported double perovskites.14

2D LFMHPs

Recently, researchers have used long-chain alkylammonium ions to separate 3D octahedra, with adjacent layers stacked on top of each other by van der Waals forces between organic chains. As shown in Fig. 3a, long hydrophobic chains provide 2D perovskites with better moisture resistance and thermal stability than 3D perovskites. Wang et al. reported emissive 2D (OCTAm) ₂SnX₄ (OCTAm = octylammonium cation) LFMHPs with a near-unity PLQY and ultrahigh stability in acidic aqueous solutions.62 Hou et al. reported that different carbon chains can affect the photoelectronic effect of 2D tin-based perovskites. They reported the synthesis of 2D LFMHPs by selecting different long-chain amines (RNH₂), as shown in Fig. 3b. (C₈H₁₇NH₂)₂- $SnBr_4$ (PLQY = 54%), $(C_{12}H_{25}NH_2)_2SnBr_4$ and $(C_{18}H_{37}NH_2)_2$ - $SnBr_4$ (PLQY = 2%) emit bright yellow light (\sim 615 nm), and $(OAm)_2SnBr_4$ (PLQY = 60%) emits excellent orange light (~628 nm). This also proves that organic carbon chains have an effect on the properties, in which the flexibility of the carbon chains

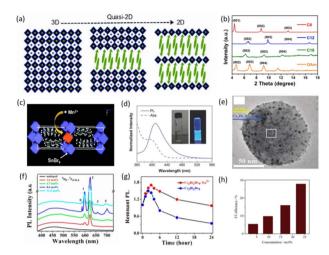


Fig. 3 (a) Perovskite lattices with different dimensions ($n = \infty$, 3D structure; n = 1, pure 2D structure; and n = defined integer, quasi-2D structure).55 Copyright 2014 Wiley-VCH. (b) XRD patterns for tin-based perovskites.56 Copyright 2019 American Chemical Society. (c) Schematic representation of 2D single-layered (C₈H₁₇NH₂)₂Sn_{1-x}Mn_xBr₄ (x = 0.25). ⁵⁷ Copyright 2020 Royal Society of Chemistry. (d) Absorption and PL spectra of Cs₃Bi₂Br₉ QD synthesis. Insets: typical optical images of the QD solution in ambient light and under 325 nm UV lamp illumination.58 Copyright 2017 Wiley-VCH. (e) TEM images of the waterinduced Cs₃Bi₂Br₉/BiOBr nanocomposites.⁵⁹ Copyright 2020 Royal Society of Chemistry. (f) Emission spectra of undoped and Eu³⁺ ionsdoped Cs₃Bi₂Br₉ QDs with different doping concentrations.⁶⁰ Copyright 2019 American Chemical Society. (g) PL intensity of undoped and Eu³⁺ ions-doped Cs₃Bi₂Br₉ PeQDs as a function of time in water.⁶⁰ Copyright 2019 American Chemical Society. (h) Energy transfer efficiency from PQDs to Sm3+ versus Sm3+ doping concentrations.61 Copyright 2020 Chinese Society of Rare Earths.

influences the arrangement of the carbon chains and the distortion of the octahedral layers. As a result, changes in binding energy, which are attributed to the arrangement of the carbon chains and distortion of the [SnBr₆]⁴⁻ octahedra, affect the band gap of tin-based LFMHPs.56 Hou et al. found that the energy level of a Mn 4T1 orbital was close to that of the selfinduced exciton, which could effectively reduce the energy loss during the energy transfer process. Therefore, they doped 2D Sn-based perovskites with Mn ions through a solid grinding method. The structure of the prepared (C₈H₁₇NH₂)₂- $Sn_{1-x}Mn_xBr_4$ is shown in Fig. 3c. Its emitted light is orange and red, and originates due to the emission of self-trapped excitons (STEs) from the host crystal and the effective emission of the dd orbital transition (${}^{4}T_{1} - {}^{6}A_{1}$) in Mn ions. However, the prepared LFMHPs exhibit PL as a single broad band due to the competition between STEs and the doped Mn d-d transition emission.⁵⁷ In order to explore the broadband emission of STEs from a 2D lead-free perovskite, Li et al. synthesized Sn-based perovskites of R_{2+x}SnI_{4+x}, which has broadband emission with the highest PLQY reaching 99%. Its stability and good photoelectronic performance make it suitable for potential application in solid-state lighting.63

In addition, other $A_3B_2X_9$ (B = Bi, Sb) LFMHPs exhibit a 2D layered structure. Leng *et al.* synthesized 2D Cs₃Bi₂Br₉ QDs with blue light emission using a modified ligand-assisted

recrystallization method. Absorption and PL spectra of Cs₃Bi₂-Br₉ QDs are shown in Fig. 3d. In the PL spectrum, an emission peak is observed at 410 nm with a FWHM of 48 nm and a PLQY of ~19.4%. Compared with single crystals, the PL peak of QDs shows a blue shift of 60 nm, indicating a strong quantum confinement effect. In addition, colloidal Cs₃Bi₂Br₉ quantum dots exhibit good stability when exposed to water due to the formation of self-passivation layers of BiOBr.58 Based on the water stability of Cs₃Bi₂Br₉ QDs, Ma et al. proposed a strategy to improve the PLQY of Cs3Bi2X9 QDs by using water-induced nanocomposites. The QDs are encapsulated in a BiOBr matrix. By optimizing the water treatment in Cs₃Bi₂Br₉ QDs, as shown in Fig. 3e, Cs₃Bi₂Br₉ QDs were encapsulated into the BiOBr matrix, which led to an enhancement of their PLQY by approximately 130% (from 20.2% to 46.4%) and improved color purity. 59 The low PLQY of Cs₃Bi₂Br₉ QDs can be attributed to the intrinsic surface defects, and the lattice defects of Cs₂Bi₂Br₉ can be reduced by the doping strategy, allowing doping ions to occupy defect states. Ding et al. doped Eu³⁺ ions into Cs₃Bi₂Br₉ ODs, which demonstrated an increased PLOY of 42.4% and multicolor emission using an improved ligand-assisted reprecipitation method. As shown in Fig. 3f, the ratio of PL intensity between Eu³⁺ ion emission and exciton emission increases with increasing Eu³⁺ doping concentration, which implies a higher effective energy transfer (ET) from Cs₃Bi₂Br₉ QDs host to the Eu³⁺ ion level. However, with the further increase of Eu³⁺ doping concentration, a self-quenching process occurs among the Eu³⁺ ions, resulting in the reduction of PL intensity of the Eu³⁺ ions. As shown in Fig. 3g, Eu³⁺-doped Cs₃Bi₂Br₉ QDs exhibit better stability in water than undoped Cs₃Bi₂Br QDs.⁶⁰ Zhu et al. also doped Sm3+ ions into Cs3Bi2Br9 QDs using an improved ligandassisted recrystallization method. The PLQY of Cs₃Bi₂Br₉ QDs increased from 10.9% to 20.8%, and the water resistance stability also significantly improved. As shown in Fig. 3h, the efficiency of ET increases with the increase of Sm³⁺ dopant concentration, indicating that doping is an effective method to improve the PLQYs of LFMHPs.61

1D LFMHPs

BX₆ octahedra of 1D perovskites are linked in chains (corner-, side-, and face-sharing) and surrounded by organic cations. In 2017, Zhou et al. prepared the 1D-structure of C₄N₂H₁₄SnBr₄ from a hydrothermal reaction of equal amounts of SnBr2 and C₄H₁₄N₂Br₂ in a mixture of 48% w/w hydrobromic acid (HBr) and 50% w/w hypochromic acid (H₃PO₂) aqueous solution, where H₃PO₂ can prevent the oxidation of Sn²⁺ ions. As shown in Fig. 4a, 1D C₄N₂H₁₄SnBr₄ has a similar structure to C₄N₂- $H_{14}PbBr_4$, where the metal halide chains of $[SnBr_4]^{2-}$ are surrounded by $C_4N_2H_{14}^{\ \ 2+}$ cations. However, unlike the intense white light emission observed in 1D lead bromide perovskite (C₄N₂H₁₄PbBr₄), 1D C₄N₂H₁₄SnBr₆ does not emit white light because the size of Sn is smaller than Pb, leading to structural distortion and suppressed recombination of excitons in 1D C₄N₂H₁₄SnBr₆.64 In terms of Mn-based LFMHPs, because of the 3d⁵ structure in Mn ions, the luminescence changes of Mn vary greatly under different crystal field environments. Mn ions

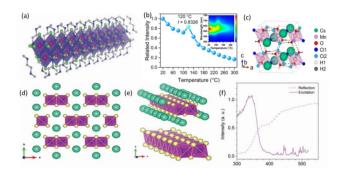


Fig. 4 (a) Views of a 1D Sn bromide wire wrapped by organic cations. 64 Copyright 2017 Wiley-VCH. (b) The variation in the integrated emission intensity ($\lambda_{\rm ex}=416$ nm) of CsMnCl $_3$ (H $_2$ O) $_2$ vs. the heating temperature (20–300 °C). Inset in the upper right shows the temperature-dependent PL spectra of CsMnCl $_3$ (H $_2$ O) $_2$. 65 Copyright 2020 Wiley-VCH. (c) Crystal structure of CsMnCl $_3$ (H $_2$ O) $_2$, hydrogen bonds (O–H) depicted as black dashed lines. 65 Copyright 2020 Wiley-VCH. (d) Structure of 1D CsCu $_2$ l $_3$ SC (green: Cs atom, yellow: I atom, dark blue: Cu atom, purple octahedron: Cu–I octahedron). 66 Copyright 2019 Wiley-VCH. (e) Cu–I D chain surrounded by Cs atoms and the independent Cu–I chain that is likea "nanowire". 66 Copyright 2019 Wiley-VCH. (f) Ultraviolet excitation spectrum collected at 568 nm and reflection spectrum. 66 Copyright 2019 Wiley-VCH.

enable green light emission in weak fields, and orange to red light emission in strong fields, which also has a positive effect on the luminescence efficiency in low-dimensional perovskites.67 Xiao et al. prepared 1D CsMnCl₃(H₂O)₂ single crystals using a typical crystallization method, and mixed isomolar MnCl₂(H₂O)₄ and CsCl in concentrated hydrochloric acid at 80 ° C. After cooling and crystallization, pink single crystals of CsMnCl₃(H₂O)₂ were obtained, which emit red light under ultraviolet (UV) excitation. The 1D crystal structure of CsMnCl₃(H₂O)₂ is shown in Fig. 4c. Each Mn²⁺ ion is coordinated with four Cl⁻ ions and two O²⁻ ions to form a twisted $[MnCl_4(H_2O)_2]^{2-}$ octahedron, which is connected by a common vertex to form a zigzag chain. In addition, each Cs⁺ ion is surrounded by eight nearest Cl ions, thus connecting the octahedra. They measured temperature-dependent PL spectra from 20 to 300 °C, as shown in Fig. 4b. The PL intensity initial decreased to 100 °C and slightly increased at 120 °C, then decreased again. This was attributed to the loss of crystal water. Compared with CsMnCl₃(H₂O)₂, the PLQY of CsMnCl₃ increases from 13% to 36%, which is due to the strong coupling of excitons with tensile vibration of OH groups, which eliminates nonradioactive recombination and quenching fluorescence.65 Pandurangan et al. adopted simple ultra-sonication and the modified ligand-assisted reprecipitation method to prepare 1D lead-free Mn halide NCs in methanol instead of DMF, so that the synthesized Mn-based perovskites are highly stable.68

A new type of Cu⁺-based LFMHP has attracted the extensive attention of researchers. Taking CsCu₂I₃ as an example, it possesses a typical 1D structure on the molecular level.⁶⁹ Huang *et al.* successfully prepared 1D CsCu₂I₃ SCs by dropping methanol into the mixture of saturated solutions (dimethyl sulfoxide (DMSO) and dimethyl formamide (DMF) at a ratio of 1:4, and dissolved a certain proportion of CsI and CuI) through the

antisolvent impregnation method. The 1D crystal structure of $CsCu_2I_3$ with isolated $[Cu_2I_3]^-$ chains in the second-dimension direction is shown in Fig. 4d and e. The emission spectra at room temperature are shown in Fig. 4f. The strong absorption peak is located at 328 nm, the optical band gap is measured as 3.78 eV, and a Stokes shift of 1.51 eV is found, indicating recombination of self-trapped excitons.66 Shi et al. dissolved different proportions of CsI and CuI in γ-butyrolactone through a rapid antisolvent crystallization process with isopropanol. After stirring the solution at 80 °C for 2 hours, the mixture was cooled naturally to room temperature. Then the supernatant of the mixture was quickly injected into isopropyl alcohol (10 mL) and stirred vigorously in the air at room temperature, producing white Cs₃Cu₂I₅ and CsCu₂I₃ precipitates immediately. Under UV excitation, blue and yellow light was emitted, respectively. The PL spectra cover almost the entire visible range of 370-750 nm. By evaluating the absorption spectra of the two products, the optical band gap of 0D Cs₃Cu₂I₅ is 3.78 eV, and that of 1D CsCu₂I₃ is smaller than 4.11 eV. Therefore, larger Stokes shifts indicate that Cu-based perovskites with a 1D structure have greater lattice distortion. The two compounds can be converted into each other by a mechanochemical reaction. Thus, standard white light emission can be obtained from the mixture of these two compounds in appropriate proportions, showing good optical properties.70

OD LFMHPs

In 0D LFMHPs, the structures of the metal halide polyhedra are independent and not connected to the surrounding cations. As a result, a flat band structure is formed, which effectively inhibits photoexcitons, leading to the emission of strong excitons and significantly promoting radiation recombination.⁷⁴ Under excitation, independent 0D structures cause lattice deformation to produce self-trapped exciton (STE) emission, thus achieving efficient luminescence. In recent years, a large number of lead-free perovskite compounds with 0D structures have been explored and synthesized, and their highly tunable emission and remarkable PLQYs have attracted the attention of many researchers.⁷⁵ In 2018, Kovalenko et al. used a simple solid-state heating approach to heat a mixture of CsBr and SnBr₂ at 350 °C for 60 hours. In this process, Cs₄SnX₆ NCs were ground in a glove box and prepared by annealing. As shown in Fig. 5a, the crystallization of Cs₄SnX₆ belongs to a trigonal crystal system, forming an R3c space group, where Cs⁺ ions occupy two different crystal positions and separate [SnBr₆]⁴⁻ octahedra.4 Compared with the CsSnBr₃ perovskite, Cs₄SnBr₆ shows excellent stability in air.41 In addition, they prepared $Cs_{4-x}A_xSn(Br_{1-y}I_y)_6$ (A = Rb, K; $x \le 1$, $y \le 1$), which exhibits 500-620 nm broadband emission. As shown in Fig. 5b, both broadband emission and long radiation lifetime indicated the formation of STEs. Zhang et al. reported a simple roomtemperature antisolvent synthesis of lead-free green-lightemitting Cs₄SnBr₆ (~524 nm) and cyan-green-light-emitting Cs₃KSnBr₆ (~500 nm) with 0D structures. By evaluating the PL, PLE and absorption spectra of Cs₄SnBr₆ and Cs₃KSnBr₆ (Fig. 5c and d), large FWHM values greater than 100 nm were

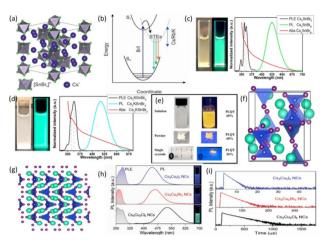


Fig. 5 (a) The crystal structure of Cs₄SnBr₆ viewed along the (111) axis with [SnBr₆]⁴⁻ octahedra (gray with green bromine atoms) separated by Cs⁺ cations (blue).4 Copyright 2018 Wiley-VCH. (b) Configurational coordinate diagram illustrating the origin of STE PL in Cs_{4-x}A_xSn(Br_{1-v}I_v)₆.4 Copyright 2018 Wiley-VCH. PL, PLE, and Abs of (c) Cs₄SnBr₆ and (d) Cs₃KSnBr₆ perovskites. Photographs of colloidal NCs captured under daylight and 302 nm UV light, respectively.30 Copyright 2020 American Chemical Society. (e) Photographs of [Na(DMSO)₂]₃SbBr₆ solution, powder, and single crystals with/without UV light.71 Copyright 2022 Wiley-VCH. (f) and (g) Crystal structure of Cs₃Cu₂I₅.⁷² Copyright 2018 Wiley-VCH. (h) PLE and PL spectra of colloidal Cs₃Cu₂X₅ NC solutions in hexane. Right insets show photographs of $Cs_3Cu_2X_5$ NC solutions under UV lamp excitation with $\lambda =$ 254 nm.73 Copyright 2019 Wiley-VCH. (i) Time-resolved PL decay spectra of Cs₃Cu₂X₅ NC solutions.⁷³ Copyright 2019 Wiley-VCH.

measured, which is desirable, indicating the existence of a strong phonon-electron coupling effect.³⁰ In addition, Stokes shifts were found to decrease from 204 nm (Cs₄SnBr₆) to 180 nm (Cs₃KSnBr₆). It may be attributed to changes in the Jahn-Teller distortion in the Sn-Br octahedra, where the elongation of axial Sn-Br bonds and the contraction of the equatorial Sn-Br bonds are included.4 However, the air stability of Sn-based 0D LFMHPs was not greatly improved, which may be due to oxidation of Sn²⁺ ions in the air. Thus, it is urgent to explore 0D LFMHPs with high-valence lead-free metal ions. 0D [Na(DMSO)₂]₃SbBr₆ NCs were synthesized by Zang et al. using the antisolvent strategy under standard atmospheric conditions, in which toluene acted as the antisolvent. During the preparation process, the precursor solution was obtained by dissolving NaBr and SbBr₃ into DMSO. Isolated [SbBr₆]⁴⁻ octahedra are surrounded by [Na(DMSO)₂]₃, and the prepared NCs exhibit bright broadband yellow-light emission under UV light excitation.71 The photoluminescence of [Na(DMSO)₂]₃SbBr₆ is regarded as originating from STEs, and its colloidal solution, powders and single crystals exhibit high PLQYs of 60%, 60%, and 56%, respectively, as shown in Fig. 5e.

 $Cs_3Cu_2X_5$ (X = Cl, Br, I), with a formula of $A_3B_2X_5$, is one of the representative 0D LFMHPs in which there are two polyhedra (triangular planes $[CuI_3]^{2-}$ and $[CuI_4]^{3-}$), as shown in Fig. 5f and g. The unique 0D structure results in the presence of strong local electrons.51 In 2018, Hosono et al. synthesized a Cs3Cu2I5 single crystal with a size of about 5 mm using a solvent-resistant

steam saturation method. Strong blue PL was observed at 445 nm and the PLQY reached 90%. A single-crystal Cs₃Cu₂I₅ thin film was successfully prepared that possesses bright blue PL with a high PLQY of 62% at room temperature, and the PLQY was almost unchanged after being stored for two months, while the PLQY in the QD film suffered from PLQY degradation, which was attributed to the aggregation of QDs.72 Wu et al. utilized a vacuum dual-source thermal deposition strategy to prepare Cs₃Cu₂I₅ thin films, which were directly deposited on a hot quartz substrate with a CsI/CuI molar ratio of 3:2. Annealing treatment was applied to the films in the deposition process, thus their crystals began to grow when precursors were attached to the substrate, avoiding the incomplete reaction of precursors and optimizing the morphologies of the Cs₃Cu₂I₅ thin films. ⁷⁶ In order to explore the tunable broadband emission of Cs₃Cu₂X₅ NCs, Quan et al. synthesized Cs₃Cu₂X₅ using the hot-injection method. As shown in Fig. 5h, the PLE and PL spectra of $Cs_3Cu_2X_5$ (X = I, Br, and Cl) NCs show clear exciton characteristics, and the emission peaks of the Cs₃Cu₂X₅ NCs change from 445 to 527 nm, which can be attributed to STE emission. Fig. 5i shows the transient PL spectra of Cs₃Cu₂I₅ NCs with a different halogen. The long lifetime of Cs₃Cu₂X₅ NCs is 1.56 μ s (X = I), 14.12 μ s (X = Br), and 135.97 μ s (X = Cl). In addition, Cs₃Cu₂I₅ NCs exhibit excellent PL stability over 45 days, while PL quenching is found in Cs₃Cu₂Br₅ and Cs₃Cu₂Cl₅ due to oxidation.73 During the preparation of Cs₃Cu₂X₅ NCs, the purity of the products was difficult to enhance. To solve this problem, Zang et al. prepared Cs₃Cu₂Cl₃ and Cs₃Cu₂Cl₅ NCs emitting bright blue and green light, respectively, by controlling the reaction temperature (70 °C and 120 °C) during the hotinjection process. The PLQY of Cs₃Cu₂I₅ was up to 87.2% and the emission spectrum was broadband. The results show that the reaction temperature can determine the final composition of Cu-based LFMHPs.77

The preparation methods of LFMHP materials

It is known that LFMHPs can be divided into 0D, 1D, 2D and 3D structures according to their atomic arrangement order, and they can also be divided into films, single crystals, powders and NCs according to their morphologies and composition. Owing to the diverse crystal configuration and low formation energy of LFMHPs, various preparation methods, such as the antisolvent reprecipitation method, the hot-injection method, and the solvent thermal method, have been proposed and developed to prepare LFMHPs. Different preparation methods have an impact on the characteristics and structures of the LFMHPs, as well as affect their optoelectronic performance. As a result, the preparation methods can determine the manufacture and performance of perovskite LEDs (PeLEDs).

Antisolvent-induced reprecipitation method

During the antisolvent reprecipitation method, the solubility of the solvent is reduced due to the introduction of antisolventinduced reprecipitation into the solution. In general, according to the polarity and electrolytic capacity of the solvent, an organic solvent can be divided into good solvents (high solubility of precursors in given solvents) and weak solvents (low solubility of precursors in given solvents). Among them, good solvents, including dimethyl sulfoxide (DMSO), N,Ngamma-hydroxybutyrolactone dimethylformamide (DMF), (GBL) and dichloromethane (DCM), generally have a high polarity, which can dissolve highly ionic precursors. The polarity of weak solvents is weak or even non-polar, thus it is difficult for them dissolve some highly ionic precursors. Examples of weak solvents include toluene, chlorobenzene, ether, methanol and n-octane.18 As shown in Fig. 6a, during the antisolvent-assisted crystallization process, mixed precursors can be dissolved efficiently in a good solvent, and it is well known that a mixture of a weak solvent and a good solvent is completely immiscible. A weak solvent enables the content of a good solvent in a precursor solution to be continuously consumed during the diffusion process, resulting in a decrease of solubility and the achievement of saturation states. As a result, precipitate of LFMHP single crystals can be obtained from solution.90 The decreased rate of solubility determines the precipitation rate of single crystals. This method is relatively simple and facile, and there are many kinds of solvent and antisolvent.52

As shown in Fig. 6b, Fang *et al.* synthesized a CsI–CuI solution using the antisolvent reprecipitation method,⁷⁰ and the resulting CsCu₂I₃ single crystals were filtered and washed

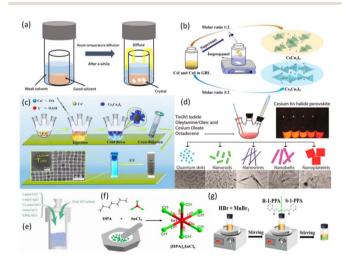


Fig. 6 (a) Diagram of antisolvent-assisted crystallization.⁹⁰ Copyright 2020 Elsevier Ltd. (b) Schematic illustration of the synthetic process for cesium copper iodide with different stoichiometric ratios.⁷⁰ Copyright 2012 Royal Society of Chemistry. (c) Schematic diagram for the colloidal synthesis of blue-light-emitting Cs₃Cu₂l₅ NCs.⁷⁹ Copyright 2020 American Chemical Society. (d) Schematic diagram of controlled synthesis procedure of perovskite Cs₂Snl₆ NCs (left) and photo of prepared Cs₂Snl₆ sample under UV light (right).⁹¹ Copyright 2016 American Chemical Society. (e) Diagram of preparation of perovskites by a hydrothermal method.¹⁴ Copyright 2021 Electrochemical Society. (f) Mechanochemical grinding solid state preparation method, and $IInCl_6I^{3-}$ unit structure of $IDPAI_3InCl_6.^{92}$ Copyright 2021 Chinese Chemical Society. (g) The experimental operation step diagram of preparation of $IRS-1-PPAI_2MnBr_4.^{93}$ Copyright 2022 Elsevier B.V.

thoroughly with isopropyl alcohol. Finally, CsCu₂I₃ single crystals exhibited strong vellow-light emission with a FWHM of ~120 nm under 305 nm UV excitation. However, when the molar ratio of CsI to CuI is changed to 3:2, the resulting precipitate is regarded as Cs₃Cu₂I₅, which shows emission of blue light with a FWHM of \sim 82 nm under UV excitation. When the molar ratio is 1:1, there are both CsCu₂I₃ and CsCu₂I₅ in the precipitate. The luminescence spectra of Cs₃Cu₂I₅ and CsCu₂I₃ show strong and broadband emission, which almost covers the whole visible spectrum range of 370-750 nm.

Another common strategy for preparing LFMHPs is the coprecipitation crystallization method, which is commonly used for growing single crystals. In 2021, Chen et al. reported the synthesis of Cs2ZrCl6 single crystals with the assistance of concentrated hydrochloric acid via a simple co-precipitation method, where CsCl, ZrOCl·8H₂O, SbCl₃ and 37% hydrochloric acid (HCl) were the raw materials. $Cs_2Zr_{1-x}Cl_6$: xSb^{3+} (x =1, 5, 10, 20%) single crystals were obtained from different molar ratios of SbCl₃ and ZrOCl·8H₂O, and they showed different PL performance. It was found that intrinsic Cs₂ZrCl₆ shows bluelight STE emission centered at 445 nm under 260 nm excitation, and the FWHM is 135 nm. Cs₂ZrCl₆ doped with 10% Sb³⁺ shows the strongest broadband blue-light emission peaks at 495 nm and red-light emission peaks at 622 nm with a PLQY of about 78%.29 Sb3+ doping was proved to facilitate the strong electron-phonon coupling in the soft crystal structure, leading to the formation of STEs.

Although the antisolvent reprecipitation method is an effective method for preparing MHPs, the antisolvent-assisted crystallization method shows a high selectivity for organic solvents with low solubility. In addition, during the synthesis process, the fast diffusion rate of a weak solvent may cause fast crystallinity, resulting in the production of metal-halide powders instead of single crystals. In comparison, the slow diffusion rate of a solvent has been found to affect the crystal quality of LFMHP single crystals.58 Furthermore, the singlecrystal growth period is slow in this process, and the crystallization process is uncontrollable, so the antisolvent-assisted crystallization method is not suitable for fabricating large-size single crystals.30,70,94

Hot-injection method

Hot injection is a rapid preparation method, in which a precursor solution is injected into a hot solution containing ligands at a high temperature (usually above 120 °C). 95 Due to its fast injection speed, when the reaction solution is saturated, fast nucleation and growth occur immediately, facilitating dispersal of the final product in solution. This synthesis method can be used to synthesize small, monodisperse and highcrystallinity NCs. The sizes, distribution, and shapes of the NCs depend on the ratios of surfactants to precursors, as well as the concentration of precursor, injection temperature, and reaction time.79 As shown in Fig. 6c, Wang et al. synthesized Cs₃Cu₂I₅ NCs using a modified hot-injection method. The synthesis process can be described simply as dissolving copper iodide precursors into cesium oleate, and cooling the mixture

after a short reaction time. Cu⁺ ions combine with Cs⁺ and I⁻ ions to form Cs₃Cu₂I₅ NCs stabilized by oleic acid (OA) and octylamine (OAM) ligands. Under excitation of UV light, the colloidal solution of NCs shows bright blue-light emission at 445 nm with a FWHM of 63 nm and a PLQY of 87%, as well as negligible PL degradation of Cs₃Cu₂I₅.91 Cesium oleate and tin iodide(w) act as precursors in the solution containing OA and OAm. Even after exposure of the cesium oleate Cs₃Cu₂I₅ to an air environment for 35 days, its stability against water and oxygen was maintained.79

Wang et al. synthesized well-structured lead-free and stable Cs₂SnI₆ NCs with different morphologies by the simple hotinjection method, as shown in Fig. 6d.91 White products were observed at first, which then turned dark-brown. The crude solution was then purified with a mixture of toluene and hexane (1/1 v/v) under ambient conditions. Finally, the NCs were dried in a bottle. When adjusting the reaction temperature and time, as well as the ratios of precursors, spherical QDs, nanorods, nanowires and nanosheets of the synthesized Cs2SnI6 are obtained.

The hot-injection method is regarded as a common method in the preparation of LFMHPs. According to previous studies about LFMHPs, the hot-injection method is usually used for the synthesis of NCs96 and QDs,70 because this method can obtain more evenly distributed products. However, there is often solvent residue on the surface of the products, which has an impact on the performance of the prepared products.94 Therefore, improving the solubility of the solvent and exploring new good solvents are required to optimize the hot-injection method.

Solvent thermal method

A hydrothermal method refers to a chemical reaction in a sealed pressure vessel with water as the solvent under high temperature and pressure conditions. According to different reaction types, it can be divided into hydrothermal oxidation, reduction, precipitation, and crystallization. Among them, the hydrothermal crystallization method is the most commonly used, and its main principle is dissolution and recrystallization. Firstly, reactants are dissolved in a hydrothermal medium in a certain proportion, facilitating ionization in solution.64 Then, the strong convection of the autoclaves enables transport of these ions to the low-temperature area, forming a saturated solution and crystallization of the precipitate. In terms of the solubility of various LFMHPs, the solvothermal method is beneficial for the preparation of LFMHPs with different structures.97 Wang et al. prepared Bi-doped Cs₂Ag_{1-x}Na_xInCl₆ using the hydrothermal method,14 in which a mixture of InCl3, CsCl, AgCl, and a small amount of BiCl3 were dissolved in hydrochloric acid solution, as shown in Fig. 6e. The solution was sealed in PTFE bottles and heated in an oven to 180 °C for 12 hours, and then cooled to 50 °C. It was found that the highest PLQY of 86.91% in Bi-doped $Cs_2Ag_{1-x}Na_xInCl_6$ was obtained when x = 0.8, and its PL spectrum was in the range of 400-780 nm. Jiang et al. also prepared Cs₂NaBiCl₆ (ref. 98) single crystals by the hydrothermal method, and studied the relationship between the

optical response and phase transition of Cs2NaBiCl6 under high pressure. Li et al. used the solvothermal method to synthesize all-inorganic lead-free perovskite $Cs_2Zr_{1-x}Te_xCl_6$ (x = 0-0.3) microcrystals (MCs).80 The prepared pure Cs2ZrCl6 MCs showed blue-light emission at 460 nm, while Cs₂Zr_{1-x}Te_xCl₆ perovskite MCs doped with Fe⁴⁺ showed bright yellow-light emission with a PLQY up to 79.46% at room temperature.

The solvothermal method can not only be used with different solvents to obtain products with different structures, but also exhibits the advantages of simple processability, low-energy consumption, and controllable particle shapes. 99 However, the product yields of LFMHPs prepared from this method are low and their purities are not high enough. 100

Other methods

In addition to the methods described above, there are many other ways to prepare LFMHPs. Zhu et al. used a modified ligand-assisted recrystallization method⁶¹ to dope Sm³⁺ ions into Cs₃Bi₂Br₉ QDs, which then exhibited effective white-light emission. Two new crystalline hybrid indium chloride materials [DAPEDA]InCl₆·Cl·H₂O and [DPA]₃InCl₆ (DAPEDA = $C_8H_{22}N_4$, DPA = $C_6H_{15}N$) were prepared by Sun et al. using a facile wet-chemistry method, as shown in Fig. 6f,92 and they exhibited strong broadband green-light emission with PLQY values of 40% and 34%, respectively. Zang et al. also used a solid mechanical grinding method to prepare 0D hybrid copper halide $(TMA)_3Cu_2Br_{5-x}Cl_x$ powders, which possess strong broadband emission and a PLQY up to 75%, as well as good stability to heat and air. Wang et al. successfully prepared a pair of lead-free manganese halide enantiomers (R/S-1-PPA)₂MnBr₄ (R/S-1-PPA = R/S-1-phenylpropane-1-amine) using a solution method, as shown in Fig. 6g.93 However, its PLQY dropped sharply when the film was prepared. 101 Therefore, the preparation technology of LFMHPs needs to be further improved.

WLEDs based on LFMHPs

In solid-state lighting, the white light of ideal light sources should be continuous and stable, and the chromaticity coordinate of ideal white light is (0.33, 0.33). Researchers often use a correlated color temperature (CCT), color rendering index (CRI), energy conversion efficiency (ECE), and lifetime to evaluate the luminous quality of white light. Various CCT values of light sources can cause different feelings to humans. CCT of warm white light is about 2700 K, neutral white light is about 4000 K, and when the CCT is above 5000 K, it is known as cold white light.105 The CRI ranges from 0 to 100, and white light with a higher CRI enables the true color of objects to be illustrated. 106 $ECE(\eta)$ represents the energy conversion efficiency in lumens/ watts and can be expressed by the formula: $\eta = \Phi_{\rm v}/P_{\rm 1}$, where $\Phi_{\rm v}$ is the total luminous flux (the energy radiated per unit of time from the source at the visible wavelength) and P_1 is the total lamp power input or radiant power emission.107 The lifetime is defined as the time it takes for the brightness to decline to a specific percentage of its initial value. 108 Directly mixing lead-based perovskites does not lead to emission of white light

due to an anion exchange reaction. Therefore, by mixing LFMHPs with other emitting materials, a reasonable device structure can be designed and fabricated to emit white light.109 The white light produced by LFMHPs can be divided into two forms: (1) multiple LED chips or emitters of different colors are connected, and perovskite electroluminescence (EL) enables ideal white light through voltage and current excitation; (2) the LFMHPs can be activated by blue or UV chips to emit highperformance white light through photoluminescence (PL). In this section, a brief description on the development of WLEDs based on LFMHPs from these two aspects is given.

Electroluminescent (EL) WLEDs based on LFMHPs

The main components of electroluminescent devices are luminescent layers; electron transport layers (ETLs), and hole transport layers (HTLs), as well as upper and lower electrodes. The two kinds of carrier recombination processes of electroluminescent devices are as follows: the first one is that electrons and holes are injected into the luminescent layer under a driving voltage, forming excitons to emit photons through radiation recombination. The second type is Förster resonance energy transfer, in which electrons or holes are not confined in the luminescent material layers, but in hole transport layers or electron transport layers, and then transferred to the luminescent layers through Förster resonance. Composite emission of photons then occurs in the luminescent layers. These two carrier recombination processes can exist simultaneously and have no influence on each other. Key indicators to evaluate an electroluminescent LED are the external quantum efficiency, current efficiency and opening voltage.

In 2018, Luo et al. reported a lead-free double perovskite $Cs_2(Ag_{0.60}Na_{0.40})InCl_6$ film that showed a high PLQY of 86%. Due to the existence of STEs, one-component warm white-light emission can be realized in Cs₂(Ag_{0.60}Na_{0.40})InCl₆. Fig. 7a shows the structure of the fabricated EL device, in which carrier injection and transport can be regulated in carrier transporting layers.16 Under driving voltages, the EL device exhibits broadband emission, demonstrating a peak current efficiency of 0.11 cd A⁻¹ (Fig. 7b). ¹⁶ To improve the quality of white light based on lead-free double perovskites, Chen et al. doped Tb3+ ions into the Cs2Na0.4Ag0.6In0.97Bi0.03Cl6 double perovskite (TDP) thin film via a solution method and the Tb³⁺ dopants were proven to enhance the restructuring of STEs in the TDP. In addition, TPD shows effective injection and carrier recombination abilities. Therefore, a WLED with TDP/host and green carbon dots (G-CDs) as emission layers was fabricated, and its structure is shown in Fig. 7c. It was found that the WLED exhibited excellent white-light emission performance, including a color coordinate of (0.328, 0.329), a CRI as high as 87.7, a CCT value of 5702 K, an EQE of 0.695%, and a high brightness of 3163 cd m⁻².19 In addition, Liu's team reported a one-component warm WLED based on an ultra-wideband MA₂CuCl₃ emitter with a visible light range of 400 to 800 nm, and the prepared electroluminescent WLED is shown in Fig. 7d. 102 The valence band position of the hole injection layer (HIL) was reduced by incorporation of 20% 4,4'-bis(carbazol-9-yl) biphenyl (CBP) into PVK (poly(9-

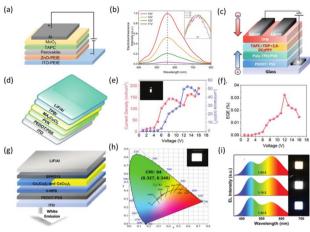


Fig. 7 (a) The electroluminescent device structure. 16 Copyright 2018 Springer Nature Limited. (b) Electroluminescence spectra at an applied voltage of 11 V, 12 V, 13 V and 14 V, respectively. The inset is the normalized spectra.¹⁶ Copyright 2018 Springer Nature. (c) Schematic illustration of white light-emitting diode (WLED) device structure.¹⁹ Copyright 2023 Wiley-VCH. (d) Device structure of MA2CuCl3 thinfilm-based LEDs.102 Copyright 2022 Wiley-VCH. (e) I-V-L characteristics of MA₂CuCl₃ LED device. 102 Inset: photograph of the LED driven by a 10 V bias. Copyright 2022 Wiley-VCH. (f) EQE versus voltage of these devices. 102 Copyright 2022 Wiley-VCH. (g) Schematic structure of WLEDs. 103 Copyright 2020 Royal Society of Chemistry. (h) CIE chromaticity diagram (inset: photograph of the white device).103 Copyright 2020 Royal Society of Chemistry. (i) EL spectra of the devices fabricated with different CsI/CuI molar ratios. The insets of (i) show a series of white-light photographs of the devices from coldwhite light to warm-white light. 104 Copyright 2020 Wiley-VCH.

vinylcarbazole)), resulting in significant white-light emission at a bias voltage of 7 to 13 V. Fig. 7e gives the current-voltbrightness (I-V-L) characteristics of the MA₂CuCl₃ LED, and the inset shows a photograph of the LED driven at a 10 V bias. The required on-voltage of the LED is about 6 V, the maximum brightness is 54 cd m⁻², and the maximum EQE is 0.035% (Fig. 7f).

However, the CRI values of reported single-component white emitters are generally small and not suitable for efficient whitelighting performance.51 Therefore, multi-component Cu-based perovskite WLEDs with STE characteristics have attracted the interest of researchers. Zhu et al. easily realized a controllable and reversible phase transition between Cs₃Cu₂I₅ and CsCu₂I₃ via solvent treatment, and achieved white-light emission. The electroluminescent device structure and CIE chromaticity diagram are shown in Fig. 7g and h, respectively. The on-voltage is only 2.9 V at 1 cd m⁻², and the maximum current efficiency is 0.11 cd A^{-1} . The EQE is 0.053%. At the same time, Shan et al. prepared a CsCu₂I₃@CsCu₂I₅ composite using different ratios of CsI and CuI, and the composite showed ideal white-light emission with cold and warm white-light tuning as shown in Fig. 7i. They produced electroluminescent WLEDs with a multilayer structure of ITO/PEDOT:PSS/poly-TPD/PVK/CsCu₂I₃@Cs₃-Cu₂I₅/TPBi/LiF/Al, and the device schematic diagram is shown in Fig. 8a. They experimented with WLEDs by creating three devices with a Csl/Cul molar ratio of 1.05:2, 1.15:2, and 1.25:

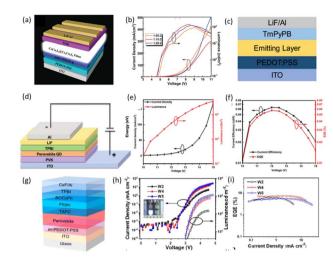


Fig. 8 (a) Schematic structure of the electrically driven WLEDs based on CsCu₂I₃@Cs₃Cu₂I₅ composite films. 104 Copyright 2020 Wiley-VCH. (b) Current density-voltage-luminance curves of WLEDs with different CsI/CuI molar ratios. 104 Copyright 2020 Wiley-VCH. (c) Schematic diagram of the WLED structure. 110 Copyright 2021 Springer Nature. (d) Structure diagram of Cs₂AgIn_{0.9}Bi_{0.1}Cl₆ QDs-based electroluminescence WLEDs. 111 (e) Dependence of the current density and luminance on the driving voltage.111 (f) Dependence of the current efficiency and EQE on the driving voltage.111 Copyright 2021 Wiley-VCH. (g) Schematic diagram of the device structure of the perovskite/ organic hybrid white LEDs. 112 (h) J-V-L (inset: photograph of working device W4) and (i) EQE-J characteristics of devices W2, W4, and W5. 112 Copyright 2022 American Chemical Society.

2, respectively. As shown in Fig. 8b, the current density-voltagebrightness curves of the three devices showed that, above the initial voltage, the current density and brightness of the devices increased sharply, yielding a maximum luminance of 145 cd m^{-2} at 8.4 V for the WLED with the Csl/Cul molar ratio of 1.15 : 2 and an EQE value of 0.15%. It is worth mentioning that the CRI value obtained was as high as 91.6.104 However, the electronic properties of cesium copper iodides are disadvantageous for LEDs because of the large effective mass of the carriers, 113 and poor charge transport due to the large band gap.114 They found that the photoelectronic properties of cesium copper iodides could be significantly enhanced by simply chemically adsorbing ether groups to the metal-halide surfaces as electron donors. Based on this strategy, Wang et al. fabricated WLEDs based on a prepared 0D Cs₃Cu₂I₅ and 1D CsCu₂I₃ mixture, as shown in Fig. 8c.110 WLEDs exhibit broadband EL spectra with a CIE coordinate of (0.44, 0.53), and display luminance up to 1570 cd m⁻² at a low voltage of 5.4 V. Perovskite quantum dots have been widely used in WLEDs because of their high quantum yields, adjustable band gap and simple preparation.111 In addition to white-light emitting perovskites as the emission layer of the device, perovskites that emit non-white light such as blue, red or green light can also be used as light-emitting layers. Zhang et al. prepared an electroluminescent WLED based on lead-free double perovskite Cs2AgIn0.9Bi0.1Cl6 quantum dots with red and purple dual-color emission. They chose PVK as the hole transport layer, and purple radiation of PVK effectively compensated for purple radiation of quantum dots, and

luminous performance remained unchanged. The device structure is shown in Fig. 8d. The current density-voltage (I-V) and light-emitting voltage (L-V) curves of QD WLEDs are shown in Fig. 8e. The on-voltage (at 1 cd m⁻²) is 10 V, and the brightness value is 34.7 cd m⁻² (15 V). As shown in Fig. 8f, the maximum current efficiency and EQE are 0.058 cd A-1 and 0.064%, respectively. Finally, they chose triphenylphosphine oxide (TPPO) to fill tiny gaps among the quantum dots, and increased the maximum brightness and EQE to 158 cd m⁻² and 0.08%, respectively.111 Su et al. combined a successively stacked pure-red-light-emitting lead-free perovskite with a sky-bluelight-emitting organic p-i-n heterojunction to achieve coordinated white-light emission. The device structure is shown in Fig. 8g, where an ultra-thin undoped organic phosphorescent intermediate layer (FIrpic) is sandwiched between a p-type hole transport layer (p-HTL) (TAPC) and an n-type electron transport layer (n-ETL) (BOCzPh) to form a sky-blue-light glowing organic p-i-n heterojunction unit. They investigated different thicknesses of perovskite layers at 50, 40 and 30 nm in devices designated as W2, W4 and W5, respectively. It can be seen from Fig. 8h that the brightness gradually increases as the thickness of the perovskite layer decreases. As shown in Fig. 8i, although W5's maximum brightness climbed to 1162 cd m⁻², its EQE peak decreased to 5.54%. By adjusting the thickness, the peak EQE of the final device is 7.35%, the brightness is 746 cd m^{-2} , the CIE coordinate is (0.424, 0.363), and the CCT value is 2868 K.112 Similarly, other perovskites with high luminous efficiency and stable red-light emission can also be applied; for example, the red LED made by Lee's team can also be used to prepare white LEDs with this strategy.¹¹⁵ It is noteworthy that lead-free perovskites with other emitters enable electroluminescent emission using this strategy. Wang et al. utilized the efficient blue-light emission of Cs₃Cu₂I₅ to realize white-light emission.⁷⁹

However, up to now, electroluminescent WLEDs based on lead-free environment-friendly metal halides are still at the initial stage, and the performance of the devices obtained is far less than that of WLEDs based on lead-based perovskites. Therefore, it is also necessary to improve the efficiencies of the electroluminescent WLEDs based on LFMHP materials to meet the requirements of various applications.

Photoluminescent (PL) WLEDs based on LFMHPs

It has been reported that a simple mixture of yellow and blue light facilitates white-light emission. In 2017, Ma et~al. reported a series of lead-free organic-methane halides ($C_4N_2-H_{14}X$) $_4SnX_6$ (X=Br, I) and (C_9NH_{20}) $_2SbX_5$ (X=Cl) with 0D structures. The yellow-light-emitting ($C_4N_2H_{14}Br$) $_4SnBr_6$ is mixed with commercial blue-light-emitting phosphors (BaMgAl $_{10}O_{17}$:Eu $^{2+}$) in different ratios. The emission spectra for the mixtures with different ratios under UV irradiation are shown in Fig. 9a. The variety of CCT values implies that the white light can be adjusted from "cold" to "warm" (Fig. 9b). When the ratio of two emitters is 1:1, the CIE coordinates of the obtained white-light emission are (0.35, 0.39), and its CCT and CRI values are 4946 K and 70, respectively. Under different operating currents, the color stability of this white-light LED is

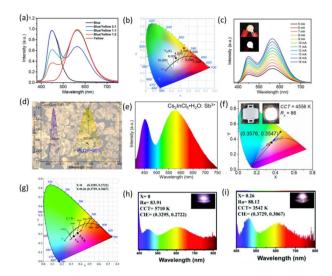


Fig. 9 (a) Emission spectra of UV-pumped LEDs with different blending ratios of blue and yellow phosphors. 116 Copyright 2017 Royal Society of Chemistry. (b) CIE coordinates and CCTs for UV-pumped LEDs plotted on the CIE 1931 chromaticity chart. 116 Copyright 2017 Royal Society of Chemistry. (c) Emission spectra of a white LED at different driving currents; insets show the operating device. 116 Copyright 2017 Royal Society of Chemistry. (d) PLE (with monitoring wavelength at 580 nm) and PL (with excitation wavelength at 340 nm) spectra of Cs₂InCl₅·H₂O:5% Sb³⁺.³⁴ Copyright 2020 American Chemical Society. (e) PL spectra of the UV-pumped WLED based on Cs₂InCl₅·H₂O:Sb³⁺ at 20 mA drive current.³⁴ Copyright 2020 American Chemical Society. (f) CIE coordinates and CCTs for the UV pumped LEDs plotted on the CIE1931 chromaticity chart.34 Copyright 2020 American Chemical Society. (g) Color coordinates and (h) image and emission spectrum of a white LED fabricated by (C₈H₁₇NH₂)₂- $Sn_{1-x}Mn_xBr_4$ (x = 0) phosphors combined with BAM commercial blue powder driven by a UV chip ($\lambda_{em}=365~\text{nm}$). For Copyright 2022 Royal Society of Chemistry. (i) Image and emission spectrum of a white LED fabricated by $(C_8H_{17}NH_2)_2Sn_{1-x}Mn_xBr_4$ (x = 0.26) phosphors combined with BAM commercial blue powder driven by a UV chip ($\lambda_{em} = 365$ nm).57 Copyright 2022 Royal Society of Chemistry.

very good, as shown in Fig. 9c.116 However, the low PLQYs of intrinsic LFMHPs still hinder their practical application in optoelectronic devices. Xia et al. doped Sb3+ ions into 0Dstructure Cs2InCl5·H2O single crystals to achieve broadband yellow-light emission with a PLQY of up to 95.5%, as shown in Fig. 9d. They then prepared WLEDs with Cs₂InCl₅·H₂O:Sb³⁺ and the blue-light-emitting BaMgAl₁₀O₁₇:Eu²⁺ phosphor in epoxy resin. Fig. 9e shows the PL spectrum of the WLED device at 20 mA current. As shown in Fig. 9f, the CIE coordinate of the fabricated WLED is (0.3576, 0.3547), corresponding to a CRI of 86, and a CCT value of 4556 K.34 However, due to the lack of red and orange emissions, WLEDs with yellow phosphors combined with blue chips usually emit cold white light. Therefore, Li et al. doped Mn2+ into yellow-light-emitting (C₈H₁₇NH₂)₂SnBr₄ to enable orange-red-light emission, and combined prepared phosphors with commercial blue phosphors to manufacture WLEDs. As shown in Fig. 9g, h and i, the color coordinates of the WLEDs based on doped metal halides are located in the warmer color region, and they exhibited an increased CRI of 88.12 and a CCT of 3542 K.57

Additionally, luminescent WLEDs can be fabricated with the assistance of mixed red, green and blue emitters. Highefficiency blue-light-emitting lead-free perovskite phosphors are firstly used to make WLEDs. Jing et al. synthesized [H₂AMPd]ZnBr₄·H₂O with strong blue-light emission and mixed it with commercial (Sr, Ca)AlSiN₃:Eu as a red phosphor to prepare WLEDs, which displayed bright white light, as shown in Fig. 10a and b, with a CCT of 5273 K, CIE chrominance coordinates of (0.33, 0.33), and a CRI of 94.5.120 Hu et al. doped Bi3+ into Cs₂ZrCl₆ to make it emit blue light and they found that Cs₂ZrCl₆:Bi³⁺ has a strong water-resistant core-shell structure and durable luminescence characteristics. After two hours of immersion in water, the luminescence intensity even increased to 115.94% of the initial level. Mixed with green and red commercial phosphors on UV chips, as shown in Fig. 10c, the WLEDs demonstrated CIE coordinates of (0.37, 0.35) and a CCT of 4179 K.121

In addition, lead-free perovskites with green-light luminescence have also been developed. Zang et al. mixed green (TBA)₂MnBr₄ single crystals with commercial red CaAlSiN₃:Eu²⁺ phosphors (630 nm) and blue InGaN chips (450 nm) to fabricate WLEDs. As shown in Fig. 10d, their CCT and CRI values were

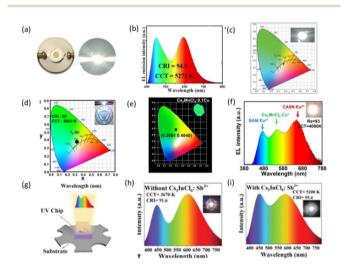


Fig. 10 (a) Photograph of obtained white LED.¹²⁰ Copyright 2023 Elsevier Ltd. (b) EL emission spectrum under 120 mA drive current. 120 mA Copyright 2023 Elsevier Ltd. (c) CIE color coordinates of the WLED device is denoted by the red star. The inset is a photo of the WLED device in operation.¹²¹ Copyright 2020 WILEY-VCH. (d) A CIE chromaticity diagram of the WLEDs, with the inset showing a photograph of a WLED. Copyright Elsevier B.V. (e) Chromaticity coordinates (1931) of Cs₂MnCl₄:0.1Cu⁺.122 (f) Electroluminescence spectrum of the WLED fabricated using a 310 nm chip and BaMgAl₁₀O₁₇:Eu²⁺, CaAlSiN₃:Eu²⁺ and Cs₂MnCl₄:0.1Cu⁺ phosphors (the inset shows the photograph of the as-packaged LED lighting). 122 Copyright 2023 Royal Society of Chemistry. (g) Schematic configuration of the WLED device fabricated from a 317 nm chip encapsulated with a mixture of phosphors consisting of $Cs_2NaInCl_6:Sb^{3+}$, $Cs_3InCl_6:Sb^{3+}$, and $Cs_2InCl_5(H_2O):Sb^{3+}$. 123 (h) Electroluminescence spectrum of a WLED based on Cs2NaInCl6:-Sb³⁺ and Cs₂InCl₅(H₂O):Sb³⁺ pumped by 317 nm chip.¹²³ (i) EL spectrum of a WLED based on Cs₂NaInCl₆:Sb³⁺, Cs₂InCl₅(H₂O):Sb³⁺, and Cs₃InCl₆:Sb³⁺ pumped by a 317 nm chip. The inset shows the corresponding EL photograph of the WLEDs. 123 Copyright 2023 Wiley-VCH GmbH.

5864 K and 80, respectively.84 In order to further enhance the green luminescence, Chen et al. doped Cu⁺ into Cs₂MnCl₄, whose CIE coordinates are displayed in Fig. 10e, and prepared WLEDs with a coating of blue BAM:Eu2+ and red CASN:Eu2+ phosphors. As shown in Fig. 10f, the prepared WLEDs have a high CRI of 93 and a low CCT of 4080 K.122 More interestingly, Jiang et al. doped Sb3+ ions into the In-based lead-free halides of $Cs_2InCl_5(H_2O):Sb^{3+}$: yellow, $Cs_3InCl_6:Sb^{3+}$: green, and Cs_2 -NaInCl₆:Sb³⁺: blue. Three-color phosphors were mixed to fabricate WLEDs, as shown in Fig. 10g. It was seen from a comparison of Fig. 10h and i that the WLEDs with Cs₃-InCl₆:Sb³⁺ have a higher CRI of 95.4.¹²³ This has greatly promoted the development of lead-free halide emitters, providing new possibilities for manufacture of high-color rendering WLEDs.

Furthermore, the mergence of WLEDs based on singlecomponent LFMHPs can solve some issues of multicomponent metal-halide WLEDs.127-133 In 2021, He Shao et al. prepared lead-free 0D K₃SbCl₆ perovskites with a blue-light emission center at 440 nm and a PLOY of 22.3%.74 By introducing Mn²⁺ ions into 0D K₃SbCl₆ perovskites, the white light was realized by controlling the doping concentration of Mn²⁺ ions. As shown in Fig. 11a, the energy transition from the ⁴T₁−⁶A₁ levels to the Mn²⁺ states is proved, which is due to the deformation of the lattices with the increase of Mn2+ ion concentration. 134 In Mn2+-K3SbCl6 NCs, STEs in the perovskites

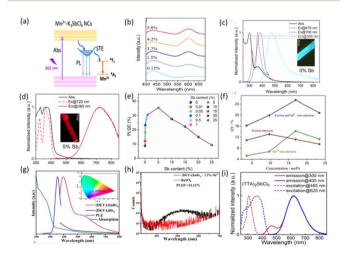


Fig. 11 (a) The proposed PL mechanism for the Mn²⁺-K₃SbCl₆ NCs.⁷⁴ Copyright 2020 Elsevier B.V. (b) PL emission spectra for Mn²⁺-K₃SbCl₆ NCs with different doping concentrations under excitation of 365 nm.74 Copyright 2020 Elsevier B.V. (c) Absorption, PLE, and PL spectra of (C₈NH₁₂)₆InBr₉·H₂O.¹²⁴ Copyright 2020 American Chemical Society. (d) Absorption, PLE, and PL spectra of $(C_8NH_{12})_6InBr_9 \cdot H_2O:5\%$ Sb sample.¹²⁴ Copyright 2020 American Chemical Society. (e) PLQE variation vs. different Sb doping contents upon 365 nm excitation.124 Copyright 2020 American Chemical Society. (f) PLQYs of exciton emission versus Sm3+ doping concentrations in Cs3Bi2Br9 PQDs.61 Copyright 2020 Chinese Society of Rare Earths. (g) PLE and PL spectra of (DETA)InBr₆ ($\lambda_{ex}=353$ nm) and (DETA)Br₃. 125 Copyright 2023 American Chemical Society. (h) PLQYs of (DETA)InBr₆:1.5%Sb³⁺. 125 Copyright 2023 American Chemical Society. (i) PLE and PL spectra of (TTA)₂SbCl₅. ¹²⁶ Copyright 2019 American Chemical Society.

together with the intrinsic transition of the dopant Mn²⁺ ions results in white-light emission. When the doping concentration of Mn²⁺ ions is 3.7%, 4.2% and 5.8%, the white-light luminescence CIE coordinates of the Mn²⁺-K₃SbCl₆ NCs were (0.29, 0.29), (0.34, 0.31) and (0.33, 0.30), respectively. In addition, as shown in Fig. 11b, they found that upon further increasing the doping concentration of Mn2+ ions, the relative emission intensity of the STEs for the intrinsic transition of Mn²⁺ ions continuously decreased due to the concentration quenching of dopants.74 The intrinsic lead-free perovskites were found to exhibit extra spectral ranges induced by incorporation of dopants, and single-component white-light emission can also be realized. Xie et al. synthesized (C₈NH₁₂)₆InBr₉·H₂O, which showed dual-band emission including strong cyan-light emission and a weak red-light emission tail (Fig. 11c). 124 The doping with Sb³⁺ ions greatly enhanced the low-energy ultra-broadband red-light emission tail, optimized the band gap structure, and promoted red-light STE emission (Fig. 11d), resulting in singlecomponent warm white-light emission with a CIE coordinates of (0.400, 0.361), a CCT of 3347 K, and a CRI of 84 at the Sb concentration of 0.1%.48 Although a 35% PLQY was obtained when the Sb³⁺ concentration was 5% (Fig. 11e), it cannot emit white light efficiently, indicating that the doping concentration may affect the efficiency of white-light emission. Pan et al. doped Sm³⁺ ions into 2D CsBi₂Br₉ QDs, which not only enhanced the PLQY from 10.9% to 20.8% (Fig. 11f), but also led to emission of tunable warm white light. The optimized whitelight emission possesses CIE coordinates of (0.296, 0.289) and a CCT of 8967 K, as well as better water resistance stability.61 Wang et al. grew 0D white-light-emitting (C₄H₁₆N₃)InBr₆ (C₄- $H_{13}N_3(DETA) = diethylenetriamine)$ LFMHPs through a simple mechanochemical method. The blue-light emission band at 400 nm and the yellow-light emission band at 550 nm are coupled together to produce cold-white-light emission with a PLOY of 1.4%. This phenomenon was caused by the radiative recombination of free excitons and STEs. The CCT and CRI of (DETA)InBr₆ are 18 059 K and 91, respectively. Its CIE coordinates are (0.26, 0.26), corresponding to cold-white-light emission (Fig. 11g).125 In order to achieve highly tunable emission, they doped with Sb³⁺ ions to regulate the photoluminescence. After Sb3+ doping, the band-edge absorption was significantly enhanced in the range of 350-430 nm. Moreover, the doping amount of Sb3+ had a great influence on the PLQYs, and a maximum PLQY of 24.12% was achieved in (DETA)InBr₆:1.5% Sb³⁺ (Fig. 11h). It can be seen that with the increase of Sb³⁺ concentration, the increase of luminescent centers as the energy receptors are transferred from the exciton band led to an enhancement of photoluminescence intensity. Li et al.97 reported 0D (TTA)₂SbCl₅ (TTA = tetraethyl ammonium) with dualband emission under high-energy photon excitation (Fig. 11i and 12a). It can be seen that under 300 nm excitation, dualband emission and an additional blue-light emission band in (TTA)₂SbCl₅ enabled single-component white-light emission with a PLQY of 68%, which was much higher than that of other low-dimensional hybrid LFMHPs.97 WLEDs based on (TTA)2-SbCl₅ exhibited a CCT of 2360 K and a CRI of 84. In addition, their excellent water resistance and thermal stability was

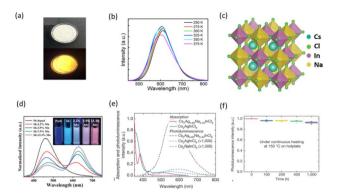


Fig. 12 (a) Photographs of $(TTA)_2SbCl_5$ powder under ambient light (top) and 365 nm UV light (bottom). ¹²⁶ Copyright 2019 American Chemical Society. (b) The PL spectra of $(TTA)_2SbCl_5$ in the range of 250–375 K. ¹²⁶ Copyright 2019 American Chemical Society. (c) Crystal structure of $Cs_2NalnCl_6$. ¹³⁵ (d) Normalized PL spectra of $Cs_2NalnCl_6$. NCs with different doping ratios. ¹³⁵ (e) Optical absorption (solid lines) and PL (dashed lines) spectra of intrinsic $Cs_2AglnCl_6$ and $Cs_2AglnCl_6$. Na_{0.40}lnCl₆. ¹⁶ Copyright 2018 Springer Nature. (f) Photoluminescence stability of $Cs_2AglnCl_6$ 0Na_{0.40}lnCl₆ against continuous heating at 150 °C on a hotplate, measured after cooling to room temperature. ¹⁶ Copyright 2018 Springer Nature.

proved, as shown in Fig. 12b.126 Double perovskites with broadband white-light emission, high absorption coefficients and fast carrier recombination rates are also of interest to researchers. 136 Cs₂NaInCl₆ is a representative cubic double perovskite, which is similar to classic lead halide perovskites, as shown in Fig. 12c. However, due to a forbidden transition in Cs₂NaInCl₆, its PLQY is very low. To enhance its optoelectronic properties, Liu et al. synthesized millimeter-scale Cs2NaInCl6 single crystals and co-doped Sb-Mn into them. The co-doped Cs2NaInCl6 was found to emit warm white light with an enhanced PLQY of 84%, as shown in Fig. 12d.135 However, blue light with a wavelength below 450 nm is harmful to human bodies and is not suitable for long-term indoor lighting. To solve this problem, Chen et al. doped Sb3+ ions into Cs2- $NaInCl_{6-x}Br_x$ double perovskites and optimized the halogen ratios. With the increase of Br/Cl ratios, the emission spectra continuously red-shifted from 445 nm (blue light) to 480 nm (cyan light), indicating that they could be employed in WLEDs.137

Furthermore, Tang et al. prepared $Cs_2(Ag_{0.60}Na_{0.40})InCl_6$ by alloying Na^+ ions into $Cs_2AgInCl_6$, and then observed whitelight emission by doping with 0.04% Bi ions. After Na alloying, an obvious exciton absorption peak appeared near 365 nm. Fig. 12e shows that the alloyed perovskites exhibited 1000 times higher emission intensity than intrinsic $Cs_2AgInCl_6$, and the highest PLQY of (86 ± 5) % was obtained when the content of Na was about 40%. The powders were directly coated onto commercial UV-LEDs to fabricate WLEDs, which showed CIE coordinates of (0.396, 0.448) and a CCT of 4054 K. When the WLEDs were operated in air for more than 1000 hours at 5000 cd m^{-2} , their luminous performance hardly changed, as shown in Fig. 12f, showing their good operating stability. For a PL WLED, stability is crucial, and Table 1 summarizes stability

Table 1 Statistics from the literature on the stability of WLED devices⁴

Materials	Color	CIE (x, y)	CCT (K)	CRI	WLED stability			
					Light	Air	Water	Ref.
(C ₄ N ₂ H ₁₄ Br) ₄ SnBr ₆	Yellow	(0.35, 0.39)	4946	70	_	$T_{98} = 6 \text{ h}$	_	116
$[Na(DMSO)_2]_3SbBr_6$	Yellow	(0.36, 0.28)	3603	85	T ₉₈ = 120 h@440 nm	$T_{57} = 130 \text{ h}$	_	71
$OTA_{2+x}SnI_{4+x}$	Yellow	(0.45, 0.38)	3300	92	$T_{98} = 25 \text{ min}@380 \text{ nm}$	_	_	63
CsMnBr ₃	Red	(0.33, 0.36)	5342	94	_	_	$T_{95} = 90 \text{ days}$	138
$[H_2AMPd]ZnBr_4 \cdot H_2O$	Blue	(0.33, 0.33)	5273	94.5	_	$T_{99} = 8 \text{ h}$	_	120
Cs ₂ ZrCl ₆ :Bi ³⁺	Blue	(0.37, 0.35)	4486	81.9	T ₉₉ = 24 h@350 nm	_	$T_{99} = 2 \text{ h}$	121
[DAPEDA]InCl ₆ ·Cl·H ₂ O:Sb ³⁺	Green	(0.33, 0.34)	5669	93.2	$T_{90} = 240 \text{ min}@450 \text{ nm}$	_	_	92
[DPA] ₃ InCl ₆ :Sb ³⁺	Green	(0.34, 0.35)	5864	80	_	$T_{50} = 240 \text{ h}$	_	84
Cs ₂ MnCl ₄ :Eu ²⁺	White	(0.33, 0.27)	_	90	_	$T_{90} = 20 \text{ h}$	_	21
K ₃ SbCl ₆ :Mn ²⁺	White	(0.29, 0.28)	8173	>80	T ₅₀ = 12 h@365 nm	_	_	74
K ₃ SbCl ₆ :Mn ²⁺	White	(0.32, 0.30)	5068	>80	_	_	_	74
K ₃ SbCl ₆ :Mn ²⁺	White	(0.35, 0.30)	4779	>80	_	_	_	74
$Cs_3Cu_2Cl_5@CsCu_2Cl_3$	White	(0.34, 0.34)	5285	94	_	$T_{64} = 60 \text{ h}$	_	77
$Cs_3Cu_2Cl_5@CsCu_2Cl_3$	White	(0.36, 0.37)	4516	89	_	$T_{98} = 120 \text{ h}$	_	139
Cs ₂ Ag _{0.6} Na _{0.4} InCl ₆ :30% Bi	White		6585	_	_	$T_{95} = 10 \text{ h}$	$T_{90} = 10 \text{ h}$	140
Cs ₂ Ag _{0.6} Na _{0.4} InCl ₆ :0.05% Bi	White	(0.40, 0.45)	4054		_	$T_{92} = 1000 \text{ h}$	_	16
$Cs_2Ag_{0.4}Na_{0.6}In_{0.9}Bi_{0.1}Cl:Ho^{3+}/Yb^{3+}$	White	(0.34, 0.36)	_	_	_	$T_{89} = 5 \text{ h}$	_	141

 $^{^{}a}$ T_{n} : required time for luminescence intensity to decrease to n% of the initial values in WLEDs.

details of reported WLEDs against light, air and water, implying the effect of emitters on the stability of WLEDs.

Challenges and perspectives

In recent years, LFMHPs have been widely utilized in solar cells, light-emitting diodes, lasers and photodetectors due to their excellent optoelectronic characteristics and properties. Importantly, the attractive luminescence performance of LFMHPs enables them to be used as emitting sources of WLEDs, facilitating potential applications in display and lighting. Therefore, researchers have paid more attention to the structures and emission mechanisms of LFMHPs, as well as optimization of WLED performance. In this work, we have reviewed structures of LFMHPs with different dimensions and common preparation methods. We focused on the principles of photoluminescent and electroluminescent WLEDs based on LFMHPs, and summarized and analyzed their performance. However, WLEDs based on LFMHPs face several problems and challenges, which may impede their further enhancement of performance and limit their potential applications. The current challenges and perspectives of WLEDs based on LFMHPs are summarized and highlighted as follows:

Light-emitting devices based on LFMHPs have been the subject of numerous studies and improvements in the performance optimization of environmentally-friendly WLEDs has been shown. LFMHPs possess high fluorescence efficiencies, narrow luminescence peaks, and adjustable emission spectra covering the entire visible range, but there are still challenges with regard to their high-efficiency photoluminescence and electroluminescence operation. For photoexcited WLEDs, their luminous efficiencies often depend on the output power of the excitation chips and the PLQYs of the LFMHPs. However, the luminous efficiencies of the photoluminescent WLEDs are far

below those of commercial sources. In addition, LFMHPs exhibit strong absorption in the ultraviolet and deep ultraviolet regions, however, short-wavelength chips (below 365 nm) used as a common excitation source for WLEDs have lower output power than blue chips, resulting in a large loss of efficiency. Therefore, enhancement of PLOYs in LFMHPs under UV excitation enables the efficiencies of WLEDs based on LFMHPs to be increased. By optimizing and minimizing the lattice deformation energy and self-trapping energy of LFMHPs, the structure of the LFMHPs can be tuned and their defects suppressed, thereby improving their PLQYs. According to previous reports, ion doping is considered to be an effective strategy to regulate the band structures of LFMHPs and improve their luminescence performance. In addition, compared with multicomponent WLEDs, fabrication of single-component WLEDs simplifies the preparation processes and can decrease the deterioration of luminous efficiencies caused by the mismatch of LFMHPs.

Apart from high luminous efficiencies, excellent stabilities of WLEDs are also required. It has been reported that the operating lifetime of an LFMHP-based photoluminescent WLED is below 1000 hours, which cannot meet the requirements of >10 000 hours for commercial lighting applications. During longterm operation of a WLED, heat is generated, and with the increase of temperature, this may lead to disintegration of the LFMHPs, which deteriorates the performance of the WLED. In addition, some LFMHPs are found to decompose when exposed to water, so it is very important to explore and optimize LFMHPs with excellent heat and water resistance. Therefore, further research on the degradation mechanism of LFMHPs is needed, and various modification and encapsulation technologies should continue to be explored. Researchers have proposed doping and coating strategies to protect LFMHPs from heat and water, thereby improving the working performance of WLEDs.

Additionally, good surface ligands can be introduced onto LFMHP NCs to reduce their sensitivity to heat and water. In summary, research of WLEDs based on LFMHPs has made remarkable progress in materials development, device design and performance improvement, but there are still many challenges, such as improving electroluminescence efficiencies and stabilities, as well as exploring materials synthesis and luminescence mechanisms. These studies are important for

promoting the development of next-generation display and

Data availability

lighting technologies.

Chemical Science

No primary research results, software or code have been included and no new data were generated or analysed as part of this review.

Author contributions

Z. Z. and S. Z. directed this review. R. T. performed the literature search and organized the content. All authors collaborated on the data analysis and participated in writing the paper.

Conflicts of interest

There are no conflicts to declare.

Acknowledgements

This work is funded by National Natural Science Foundation of China (No. 11974063); Young Elite Scientists Sponsorship Program by CAST (No. 2022QNR001).

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